To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RENESAS

MOS FIELD EFFECT TRANSISTOR

μPA1744TP

SWITCHING
N-CHANNEL POWER MOS FET

DESCRIPTION

The μPA1744TP is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for high voltage applications such as DC/DC converter.

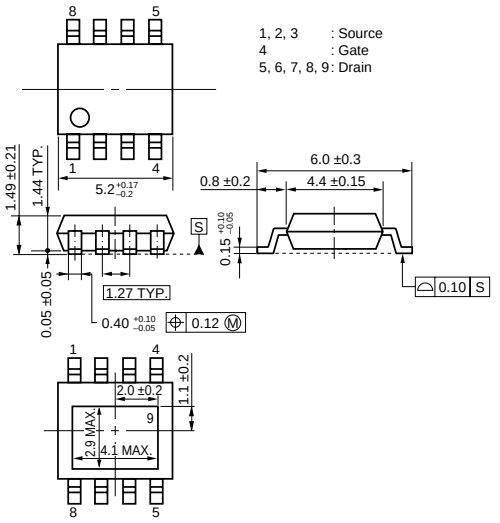
FEATURES

- Low on-state resistance
  $R_{DS(on)}$ = 30 mΩ MAX. (V_{GS} = 10 V, I_D = 5.0 A)
- Low input capacitance
  C_{iss} = 3400 pF TYP. (V_{DS} = 10 V, V_{GS} = 0 V)
- Built-in gate protection diode
- Small and surface mount package (Power HSOP8)

ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA1744TP	Power HSOP8

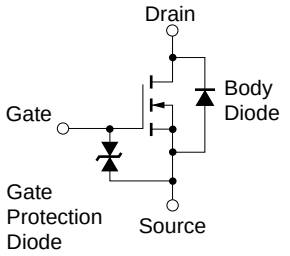
PACKAGE DRAWING (Unit: mm)



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, Unless otherwise noted, all terminals are connected.)

Drain to Source Voltage (V_{GS} = 0 V)	V_{DSS}	100	V
Gate to Source Voltage (V_{DS} = 0 V)	V_{GSS}	±20	V
Drain Current (DC) (T_C = 25°C)	$I_{D(DC)}$	±10	A
Drain Current (pulse) **Note1**	$I_{D(pulse)}$	±30	A
Total Power Dissipation (T_C = 25°C)	P_{T1}	39	W
Total Power Dissipation (T_A = 25°C) **Note2**	P_{T2}	3.0	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature	T_{stg}	–55 to +150	°C
Single Avalanche Current **Note3**	I_{AS}	10	A
Single Avalanche Energy **Note3**	E_{AS}	10	mJ

EQUIVALENT CIRCUIT



Notes 1. PW ≤ 10 μs, Duty Cycle ≤ 1%

2. Mounted on glass epoxy board of 1 inch x 1 inch x 0.8 mm

3. Starting T_{ch} = 25°C, V_{DD} = 50 V, R_G = 25 Ω, V_{GS} = 20 → 0 V, L = 100 μH

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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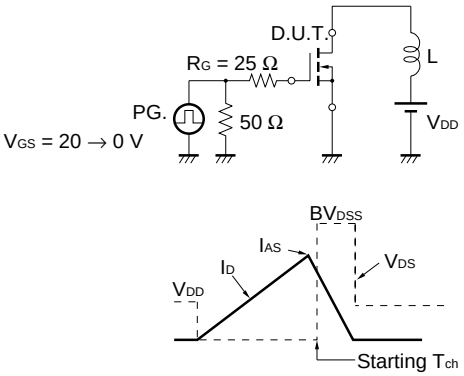
ELECTRICAL CHARACTERISTICS (T_A = 25°C, Unless otherwise noted, all terminals are connected.)

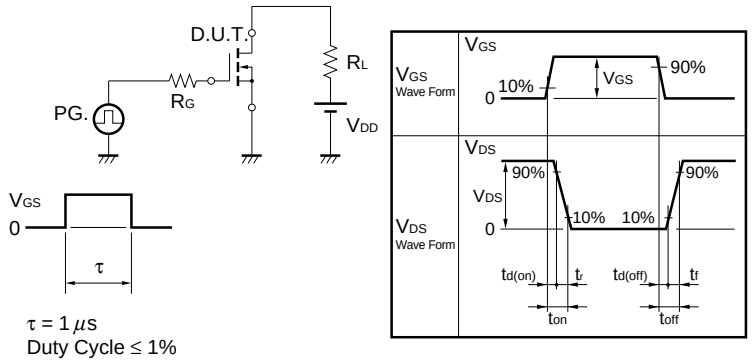
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 100 V, V_{GS} = 0 V			10	μA
Gate Leakage Current	I_{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V			±10	μA
Gate Cut-off Voltage	$V_{GS(off)}$	V_{DS} = 10 V, I_D = 1 mA	2.5	3.0	3.5	V
Forward Transfer Admittance **Note**	$\|y_{fs}\|$	V_{DS} = 10 V, I_D = 5.0 A	7	14		S
Drain to Source On-state Resistance **Note**	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 5.0 A		23	30	mΩ
Input Capacitance	C_{iss}	V_{DS} = 10 V		3400		pF
Output Capacitance	C_{oss}	V_{GS} = 0 V		390		pF
Reverse Transfer Capacitance	C_{rss}	f = 1 MHz		200		pF
Turn-on Delay Time	$t_{d(on)}$	V_{DD} = 50 V, I_D = 5.0 A		22		ns
Rise Time	t_r	V_{GS} = 10 V		10		ns
Turn-off Delay Time	$t_{d(off)}$	R_G = 10 Ω		55		ns
Fall Time	t_f			7		ns
Total Gate Charge	Q_G	V_{DD} = 80 V		66		nC
Gate to Source Charge	Q_{GS}	V_{GS} = 10 V		12		nC
Gate to Drain Charge	Q_{GD}	I_D = 10 A		22		nC
Body Diode Forward Voltage **Note**	$V_{F(S-D)}$	I_F = 10 A, V_{GS} = 0 V		0.8		V
Reverse Recovery Time	t_{rr}	I_F = 10 A, V_{GS} = 0 V		65		ns
Reverse Recovery Charge	Q_{rr}	di/dt = 100 A/μs		170		nC

Note Pulsed: PW ≤ 350 μs, Duty Cycle ≤ 2%

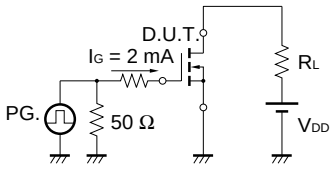
TEST CIRCUIT 1 AVALANCHE CAPABILITY



TEST CIRCUIT 2 SWITCHING TIME

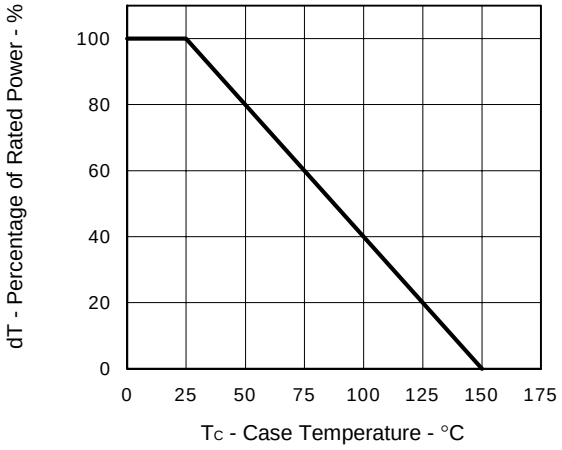


TEST CIRCUIT 3 GATE CHARGE

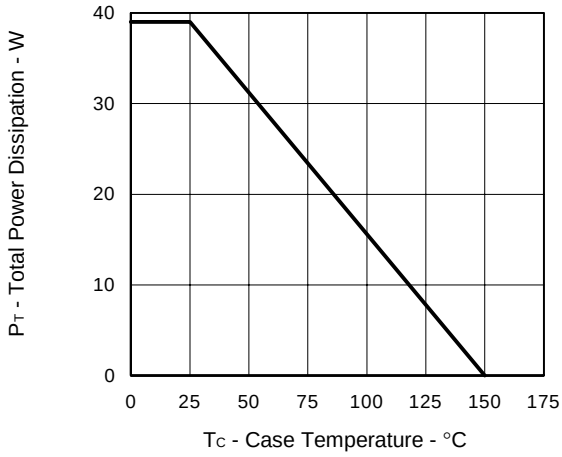


TYPICAL CHARACTERISTICS (T_A = 25°C, Unless otherwise noted, all terminals are connected.)

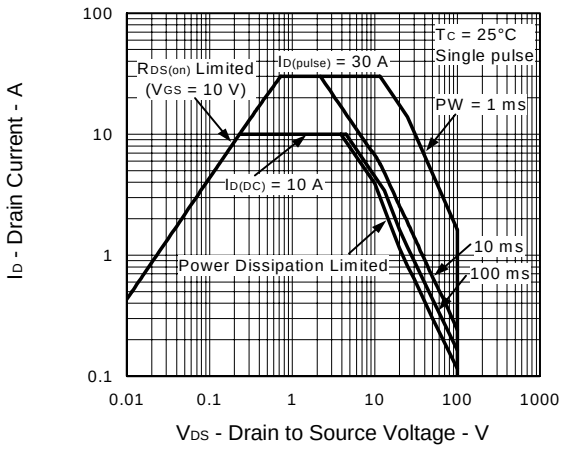
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



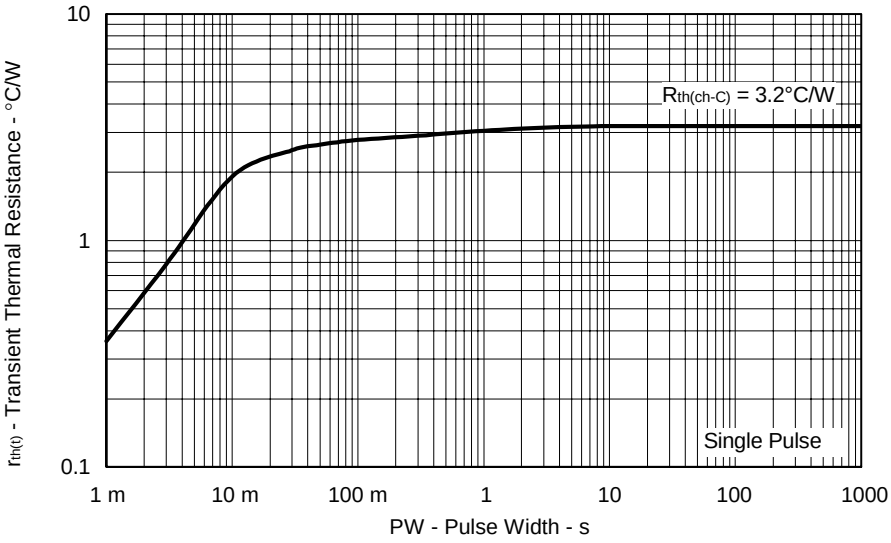
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



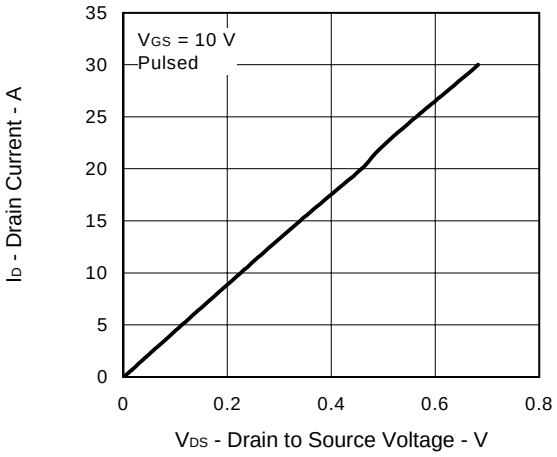
FORWARD BIAS SAFE OPERATING AREA



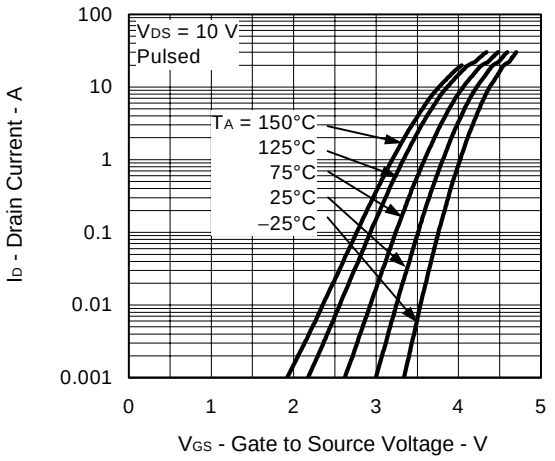
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



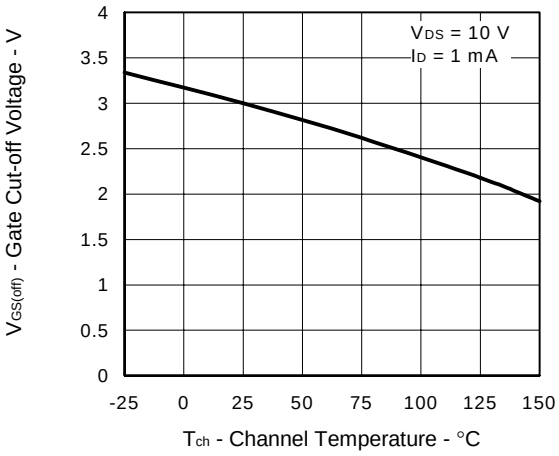
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



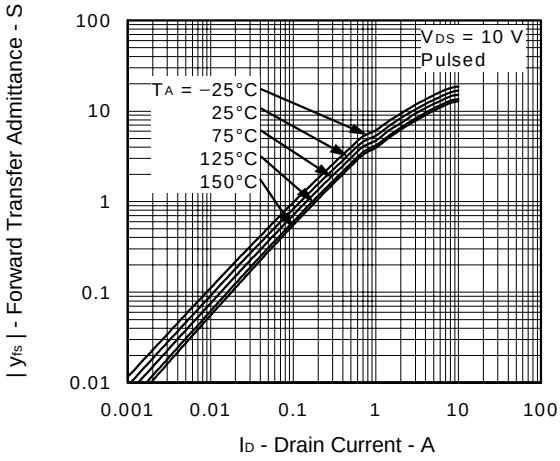
FORWARD TRANSFER CHARACTERISTICS



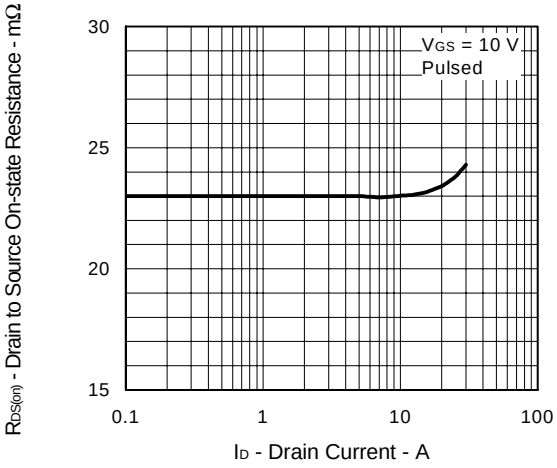
GATE CUT-OFF VOLTAGE vs.
CHANNEL TEMPERATURE



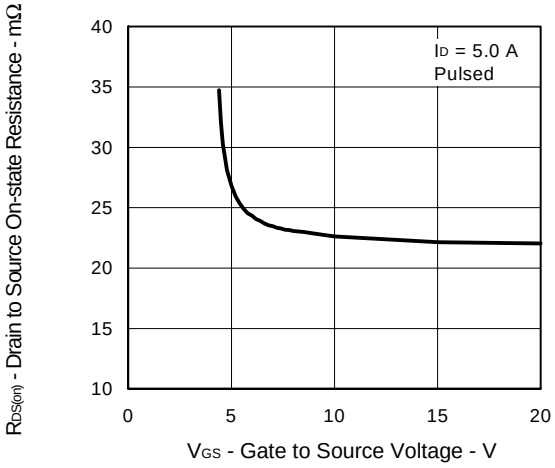
FORWARD TRANSFER ADMITTANCE vs.
DRAIN CURRENT



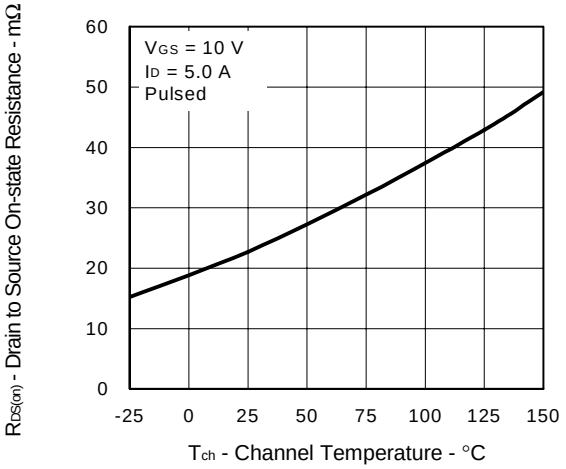
DRAIN TO SOURCE ON-STATE RESISTANCE
vs. DRAIN CURRENT



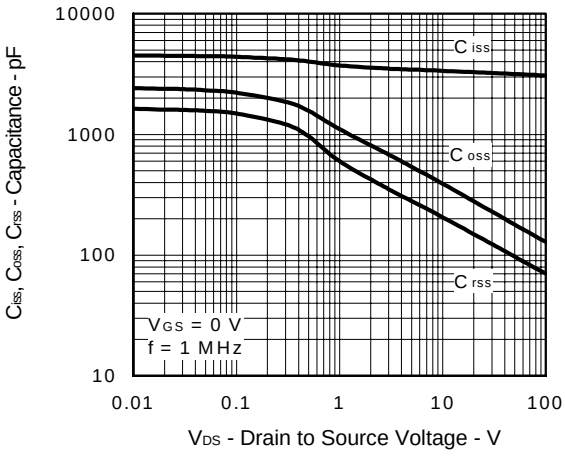
DRAIN TO SOURCE ON-STATE RESISTANCE
vs. GATE TO SOURCE VOLTAGE



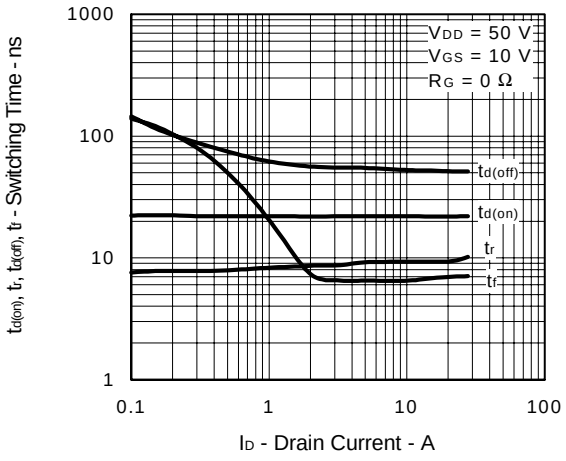
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



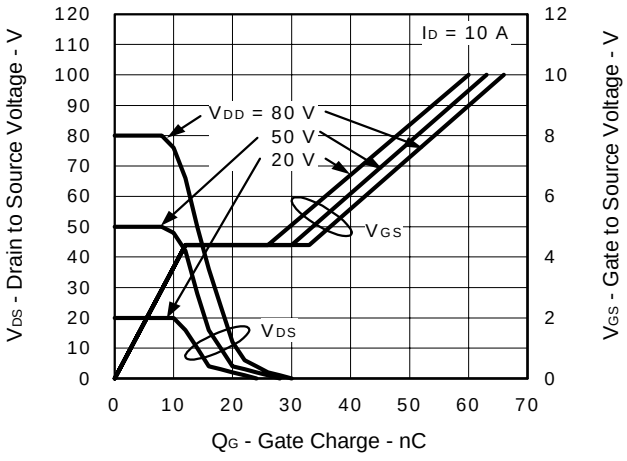
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



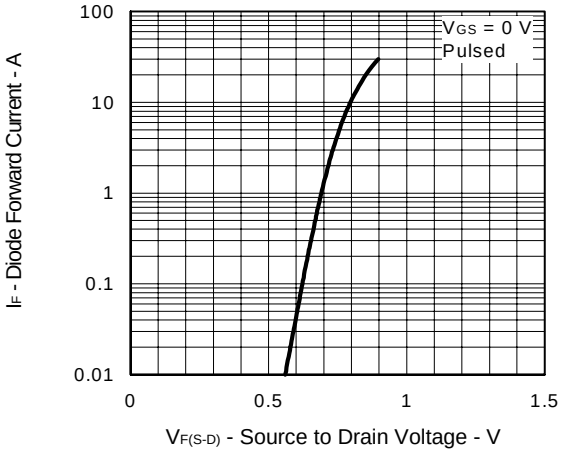
SWITCHING CHARACTERISTICS



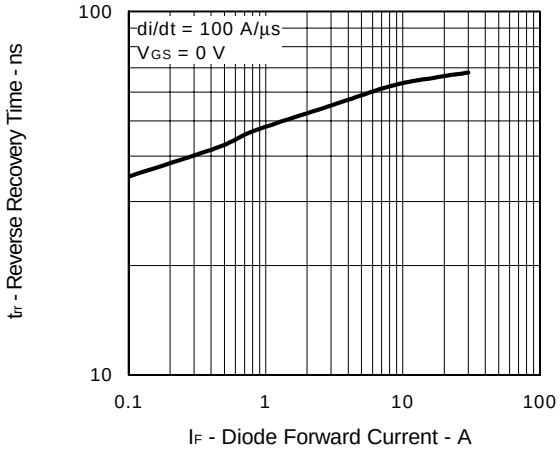
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



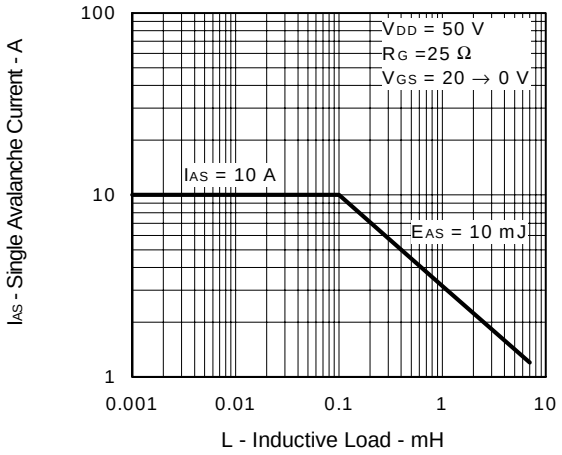
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



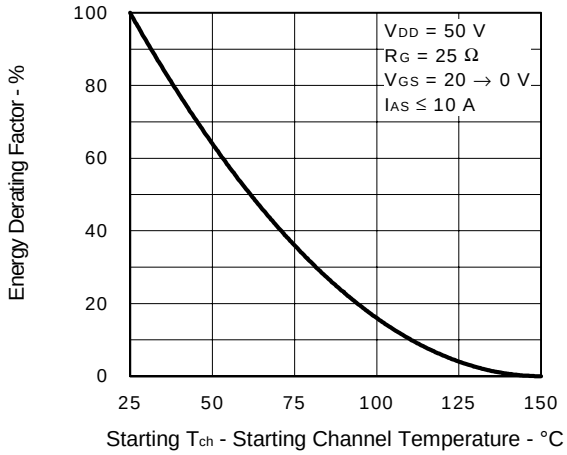
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



SINGLE AVALANCHE CURRENT vs.
INDUCTIVE LOAD



SINGLE AVALANCHE ENERGY
DERATING FACTOR



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